Micropower Ultra-Sensitive Hall-Effect Switch

Features and Benefits

- Micropower operation
- Operation with either north or south pole—no magnetic orientation required during assembly
- 1.65 to 3.5 V battery operation
- Chopper stabilization
  - Superior temperature stability
  - Extremely low switchpoint drift
  - Insensitive to physical stress
- Solid state reliability
- Small size: WLCSP (≈ 1 mm × 1 mm × 0.5 mm)
- Complementary, push-pull outputs eliminate need for pull-up resistor

Package: 4 pin WLCSP (suffix CG)

Not to scale

Description

The A1172 is an ultra-sensitive, pole-independent Hall-effect switch with a latched digital output. It features operation at low supply currents and voltages, making it ideal for battery-operated electronics. The 1.65 to 3.5 V operating supply voltage and unique clocking algorithm reduce the average operating power requirements to less than 15 µW with a 2.75 V supply.

The A1172 has two push-pull output structures. Omnipolar activation for the output function is available on each output structure. As such, either a north or south pole of sufficient strength turns the available outputs off or on. The A1172 contains two complementary outputs. Therefore, for a fixed magnetic field, one output will be in a high voltage state and one output will be in a low voltage state.

Improved stability is made possible through dynamic offset cancellation using chopper stabilization, which reduces the residual offset voltage normally caused by device overmolding, temperature dependencies, and thermal stress. This device

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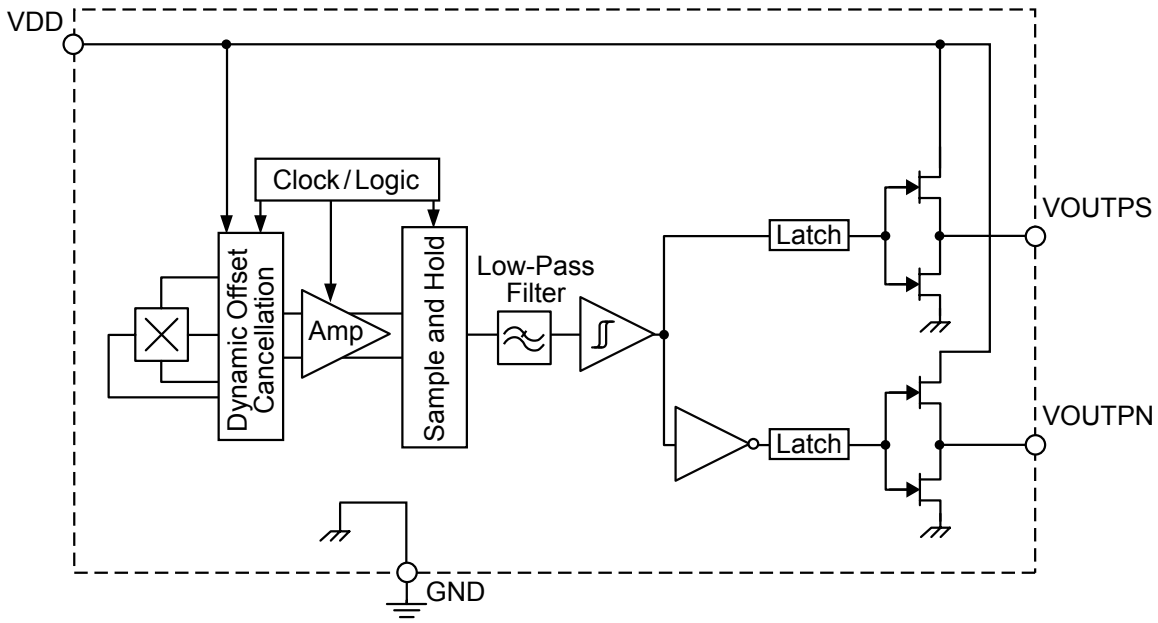
Engineering samples available on a limited basis. Contact your local sales or applications support office for additional information.

Functional Block Diagram



Description (continued)

includes, on a single silicon chip, a Hall-voltage generator, a small-signal amplifier, chopper stabilization, a latch, and a MOSFET output.

The A1172 device offers magnetically optimized solutions, suitable for most applications. The wafer level chip scale package (WLCSP) is approximately only 1 mm by 1 mm by 0.5 mm. This package is smaller than most plastic packages and reduces the printed circuit board area consumed by micropower Hall-effect switches.

Selection Guide

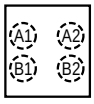
Part Number	Package	Pb-free	Packing*
A1172ECGLT	4 bumped wafer-level chip-scale package (WLCSP)	Pb-free chip with high-temperature solder balls (RoHS compliant)	4000 pieces per reel

*Contact Allegro for additional packing options.

Absolute Maximum Ratings

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V_{DD}		5	V
Reverse Supply Voltage	V_{RDD}		–0.3	V
Output Off Voltage	V_{OUTx}		5	V
Reverse Output Voltage	V_{ROUTx}		–0.3	V
Output Current	$I_{OUTx(Sink)}$		–1	mA
	$I_{OUTx(Source)}$		1	mA
Magnetic Flux Density	B		Unlimited	G
Operating Ambient Temperature	T_A	Range E	–40 to 85	°C
Maximum Junction Temperature	T_J(max)		165	°C
Storage Temperature	T_{stg}		–65 to 170	°C

Pin-out Diagram



(Bump-down view)

Terminal List Table

Name	Number	Function
VOUTPS	A1	Push-pull output
VOUTPN	A2	Inverted push-pull output
GND	B1	Ground
VDD	B2	Connects power supply to chip

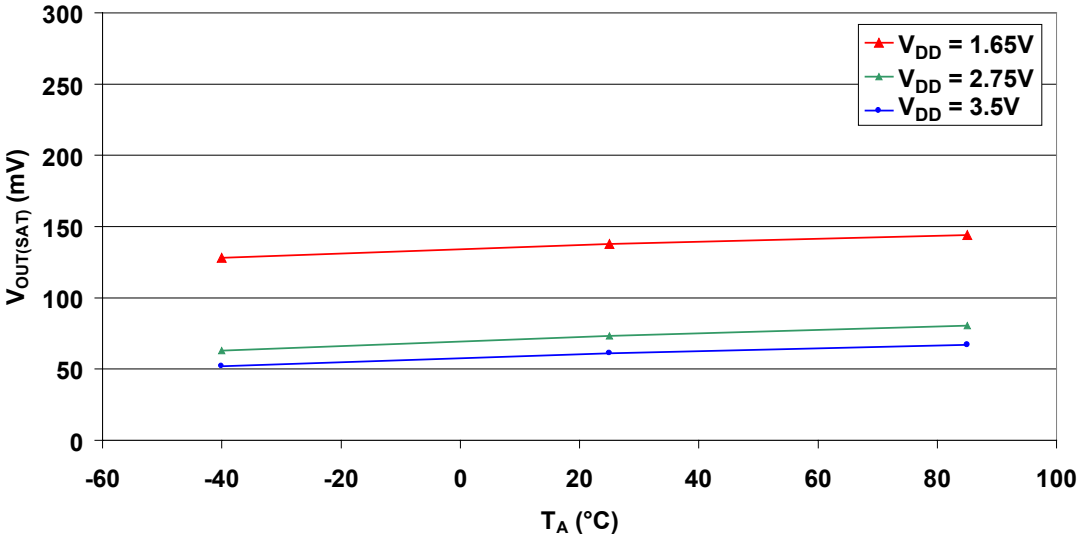
OPERATING CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Min.	Typ.[1]	Max.	Units
Electrical Characteristics valid over full operating voltage range and T_A = 25°C						
Supply Voltage Range[2]	V_{DD}	Operating, T_A= 25°C	1.65	–	3.5	V
Output On Voltage	$V_{OUT(SAT)}$	NMOS on, I_{OUT} = 1 mA, V_{DD} = 2.75 V	–	100	300	mV
	$V_{OUT(HIGH)}$	PMOS on, I_{OUT} = 1 mA, V_{DD} = 2.75 V	V_{DD}–300	V_{DD}–100	–	mV
Mode Cycle Period	t_{Period}		–	50	100	ms
Chopping Frequency	f_C		–	200	–	kHz
Supply Current	$I_{DD(EN)}$	Chip awake (enabled)	–	–	2.0	mA
	$I_{DD(DIS)}$	Chip asleep (disabled)	–	–	8.0	µA
	$I_{DD(AV)}$	V_{DD} = 1.80 V	–	4	8	µA
		V_{DD} = 3.5 V	–	6	12	µA
Magnetic Characteristics[3] at T_A = 25°C and 1.8 V ≤ V_{DD} ≤ 3.5 V						
Operate Point	B_{OPS}		–	32	55	G
	B_{OPN}		–55	–32	–	G
Release Point	B_{RPS}		6	26	–	G
	B_{RPN}		–	–26	–6	G
Hysteresis	B_{HYS}	$B_{HYS} = B_{OPX} - B_{RPX}$	–	6	–	G

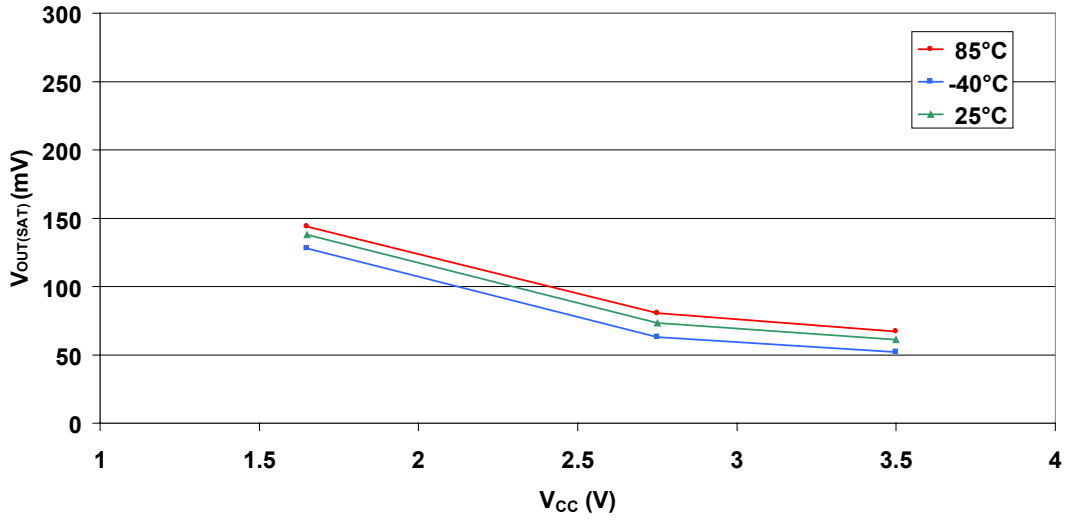
[1]Typical values at V_{DD} = 2.75 V. Performance may vary for individual units, within the specified maximum and minimum limits.
[2]Magnetic operate and release points vary with supply voltage.
[3]1 gauss (G) is exactly equal to 0.1 millitesla (mT).

Operating Characteristics

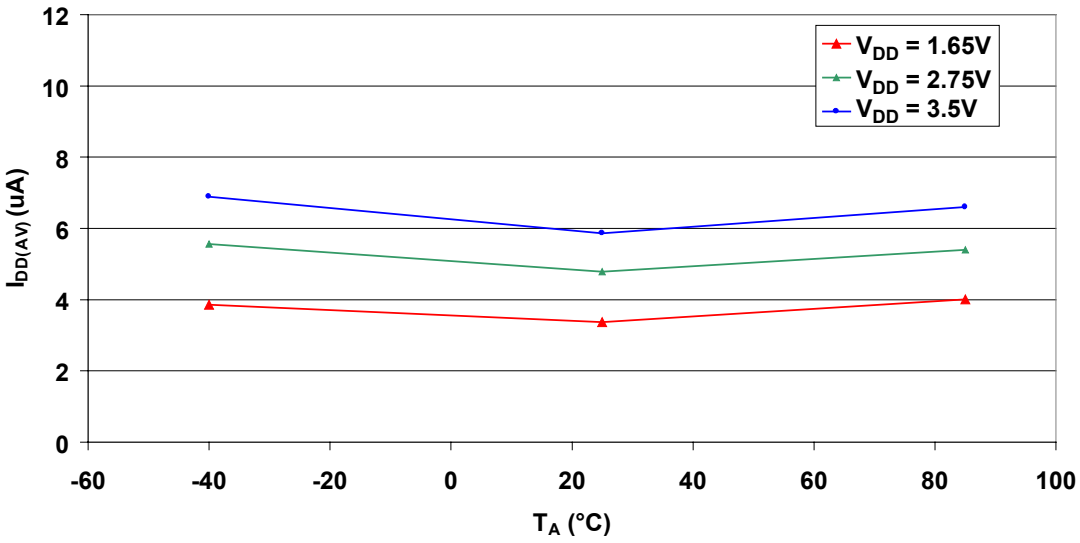
Saturation Voltage versus Temperature



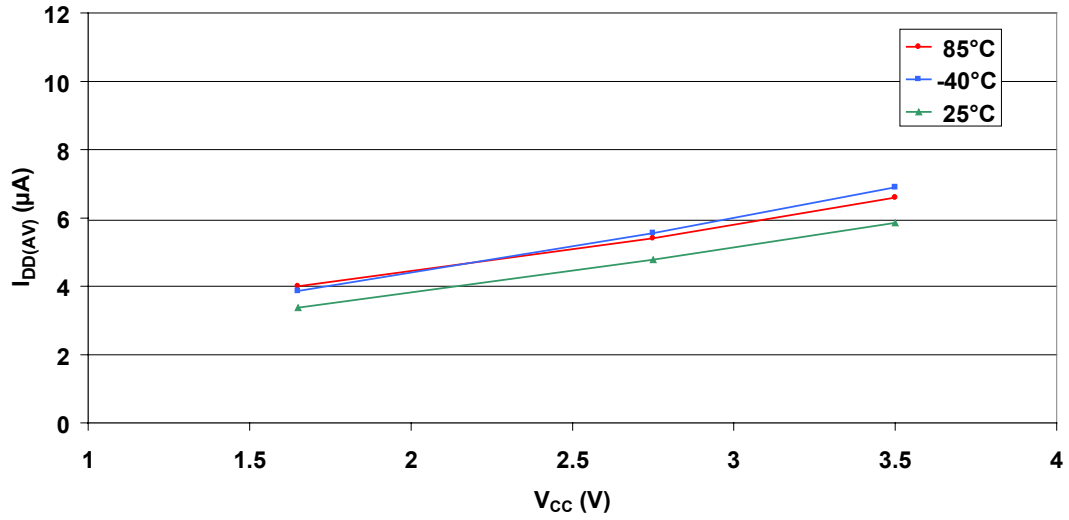
Saturation Voltage versus Supply Voltage



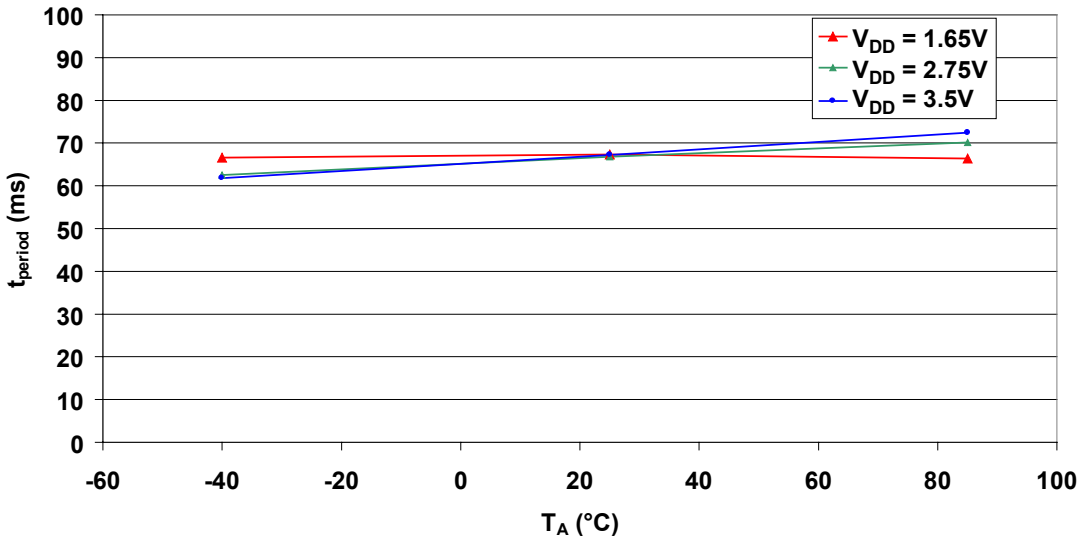
Average Supply Current versus Temperature



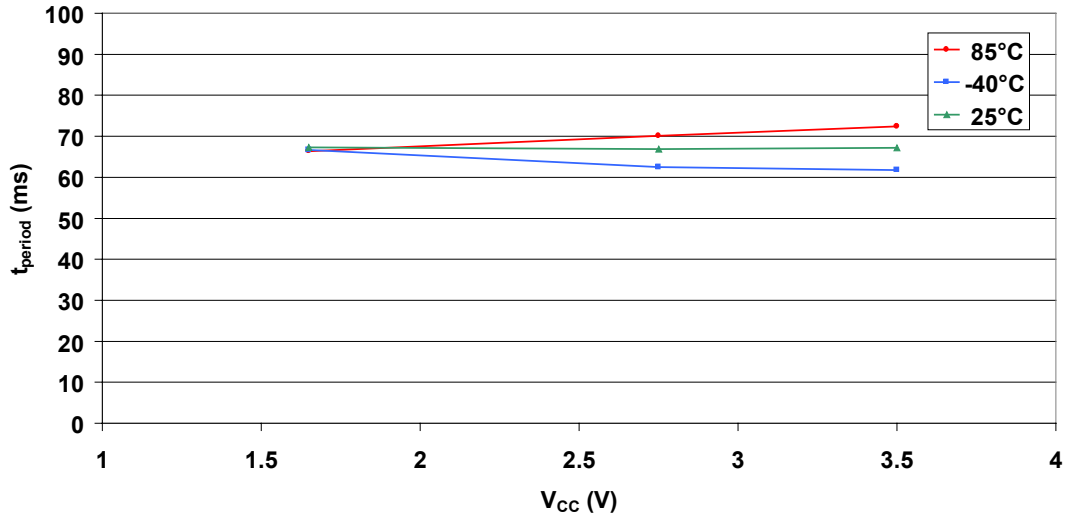
Average Supply Current versus Supply Voltage



Period versus Temperature



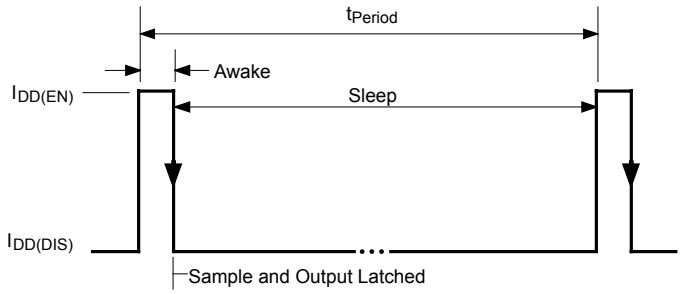
Period versus Supply Voltage



Functional Description

Low Average Power

Internal timing circuitry activates the sensor for 50 µs and deactivates it for the remainder of the period (50 ms). A short awake time allows stabilization prior to the sensor sampling and data-latching on the falling edge of the timing pulse. The output during the sleep state is latched in the last sampled state. The supply current is not affected by the output state.



Operation

The VOUTPS output switches low (turns on) when a magnetic field perpendicular to the Hall sensor exceeds the operate point, B_{OPS} (or is less than B_{OPN}). After turn-on, the output voltage is $V_{OUT(SAT)}$. The output transistor is capable of sinking current up to the short circuit current limit, I_{OM}, which is a minimum of 1 mA. When the magnetic field is reduced below the release point, B_{RPS} (or increased above B_{RPN}), the device output switches high (turns off). The pull-up transistor brings the output voltage to $V_{OUT(HIGH)}$.

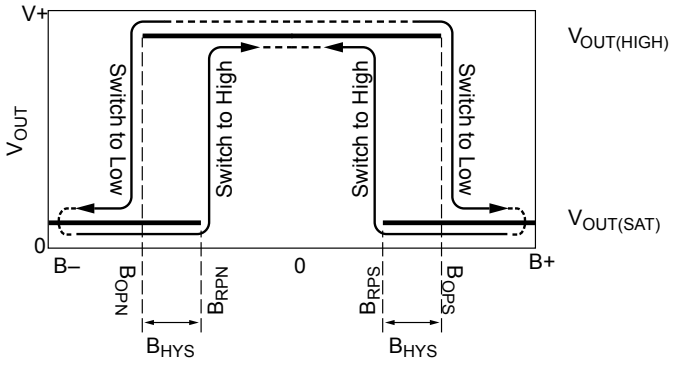
VOUTPN operates with the opposite output polarity. That is, the output is low (on) in the absence of a magnetic field. The output goes high (turns off) when sufficient field, of either north or south polarity, is presented to the device.

The difference in the magnetic operate and release points is the hysteresis, B_{HYS}, of the device. This built-in hysteresis allows clean switching of the output even in the presence of external mechanical vibration and electrical noise.

The push-pull outputs are capable of sourcing or sinking a maximum of 1 mA.

Powering-on the device in a hysteresis region, between B_{OPX} and B_{RPX}, allows an indeterminate output state. The correct state is attained after the first excursion beyond B_{OPX} or B_{RPX}.

(A) VOUTPS



(B) VOUTPN

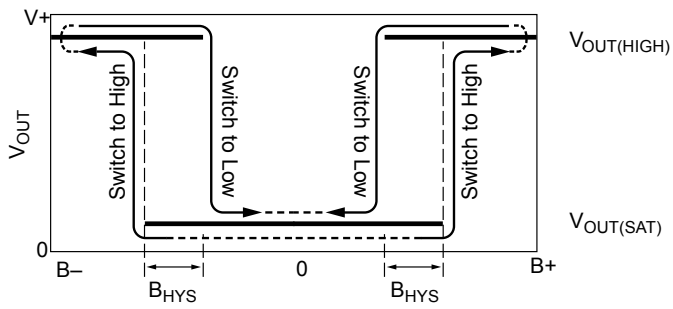


Figure 1. Switching Behavior of Omnipolar Switches. On the horizontal axis, the B+ direction indicates increasing south polarity magnetic field strength, and the B– direction indicates decreasing south polarity field strength (including the case of increasing north polarity).

Applications

It is strongly recommended that an external bypass capacitor be connected (in close proximity to the Hall sensor) between the supply and ground of the device to reduce both external noise and noise generated by the chopper stabilization technique. As is shown in figure 2, a 0.1 µF capacitor is typical.

Extensive applications information on magnets and Hall-effect sensors is available in the following notes:

- Hall-Effect IC Applications Guide, AN27701
- Hall-Effect Devices: Gluing, Potting, Encapsulating, Lead Welding and Lead Forming AN27703.1
- Soldering Methods for Allegro Products (SMD and Through-Hole), AN26009

All are provided in Allegro Electronic Data Book, AMS-702, and on the Allegro Web site, www.allegromicro.com.

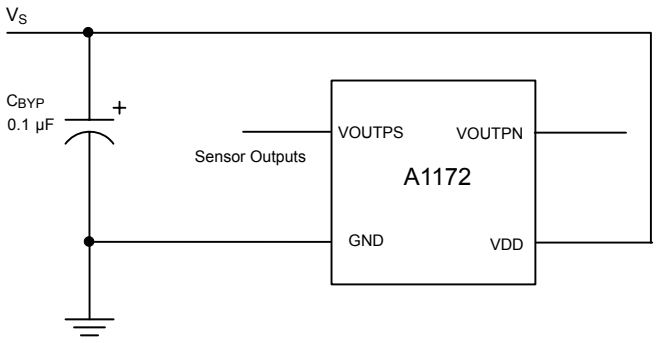
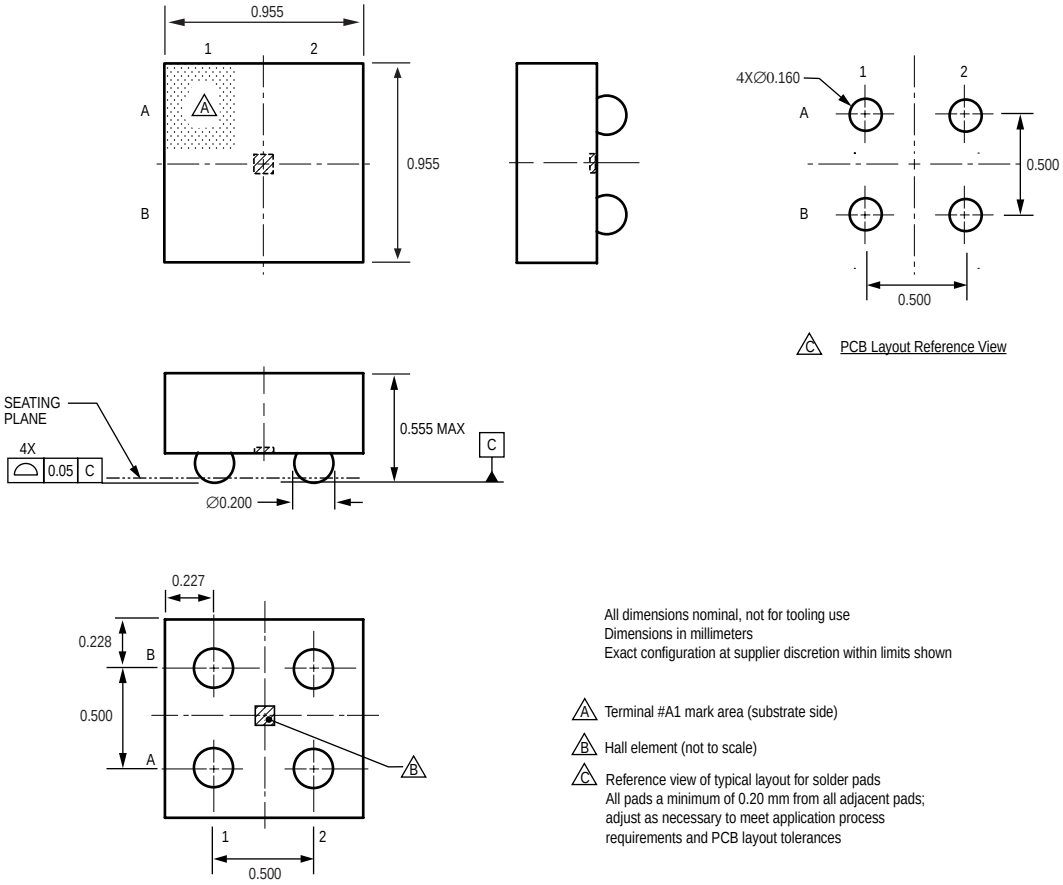


Figure 2. Typical Application Circuit

Package CG, 4-Bump WLCSP



The products described herein are manufactured under one or more of the following U.S. patents: 5,045,920; 5,264,783; 5,442,283; 5,389,889; 5,581,179; 5,517,112; 5,619,137; 5,621,319; 5,650,719; 5,686,894; 5,694,038; 5,729,130; 5,917,320; and other patents pending.

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